Near Threshold π^0 Electroproduction at High Q^2

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- Motivation
- Historical background
- Theoretical predictions
- Results from CLAS
- Summary

Motivation: Theoretical and Experimental

Processes

$$e + p \rightarrow e + \pi^{0} + p$$

$$e + p \rightarrow e + \pi^{+} + n$$

- Theoretical:
 - New extensions of low energy theorems at high Q^2 (Braun *et al*)
 - New generalized form factors $G_1(Q^2)$ and $G_2(Q^2)$
 - Axial form factor $G_A(Q^2)$: Fourier transform of the axial charge distribution in the proton that is probed via axial current

$$J^a_{5\mu}\sim \bar{q}\gamma_\mu\gamma_5\lambda^a q$$

- Experimental:
 - Previous experiments limited to $Q^2 < 1 \,\mathrm{GeV}^2$
 - No data exists for Q^2 between $1 10 \,\mathrm{GeV}^2$



Historical Background: Threshold Physics

- For $Q^2 = 0 \,\mathrm{GeV}^2$
 - Low-Energy Theorems (LETs) (Kroll-Ruderman, 1954)
 - Axial form factor G_A

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 - Perturbative QCD (pQCD) factorization methods (Pobylitsaet~al, 2001)

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 - Axial form factor G_A
- For $Q^2 \gtrsim 10 \,\mathrm{GeV}^2$
 - Perturbative QCD (pQCD) factorization methods (Pobylitsaet~al, 2001)
- For $Q^2 \sim 1 10 \,\mathrm{GeV}^2$
 - Light Cone Sum Rule (LCSR) approach
 - Reproduce LET predictions for $Q^2 \sim 1 \, {\rm GeV}^2$ and pQCD predictions for $Q^2 \to \infty$
 - Predictions of spatial distribution of the axial charge (G_A) and two new generalized form factors $G_1^{\pi N}$ and $G_2^{\pi N}$ (Braun *et al*, 2008)

Correlation function:

$$\int dx \, e^{-iqx} \langle N(P')\pi(k)|j^{\rm em}_{\mu}(0)|p(P)\rangle$$



At threshold, only S-wave contribution

$$\langle N(P')\pi(k)|j_{\mu}^{\rm em}(0)|p(P)\rangle \propto \bar{N}(P')\gamma_{5} \left\{ (\gamma_{\mu}q^{2} - q_{\mu}q)\frac{1}{m_{N}^{2}}G_{1}^{\pi N}(Q^{2}) - \frac{i\sigma_{\mu\nu}q^{\nu}}{2m_{N}}G_{2}^{\pi N}(Q^{2}) \right\} p(P)$$

- S-wave: generalized form factors from LCSR $(G_1^{\pi N} \text{ and } G_2^{\pi N})$
- Related to S-wave multipoles: E_{0+} and L_{0+}

Braun et al. Phys. Rev. D (2008).

LET Form Factors: At Threshold

At threshold, the differential cross section in terms of S-wave multipoles

$$\left. \frac{d\sigma_{\gamma^*}}{d\Omega_{\pi}} \right|_{\mathrm{th}} \propto \left[(E_{0+}^{\pi N})^2 + \epsilon \frac{Q^2}{(\omega_{\gamma^*}^{\mathrm{th}})^2} (L_{0+}^{\pi N})^2 \right]$$

Relate the multipoles to the generalized form factors

$$E_{0+}^{\pi N} \propto \frac{Q^2 \sqrt{Q^2 + 4m_N^2}}{m_N^3 f_\pi} G_1^{\pi N} \qquad \qquad L_{0+}^{\pi N} \propto \frac{Q^2 \sqrt{Q^2 + 4m_N^2}}{m_N^3 f_\pi} G_2^{\pi N}$$

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LET expressions for the form factors at <u>threshold</u> can be related to the elastic form factors and the axial form factor:

$$\frac{Q^2}{m_N^2} G_1^{\pi^0 p} = \frac{g_A}{2} \frac{Q^2}{(Q^2 + 2m_N^2)} G_M^p \qquad \frac{Q^2}{m_N^2} G_1^{\pi^+ n} = \frac{g_A}{\sqrt{2}} \frac{Q^2}{(Q^2 + 2m_N^2)} G_M^n + \frac{G_A}{\sqrt{2}} G_2^{\pi^0 p} = \frac{2g_A m_N^2}{Q^2 + 2m_N^2} G_E^p \qquad G_2^{\pi^+ n} = \frac{2\sqrt{2}g_A m_N^2}{Q^2 + 2m_N^2} G_E^n$$

LET Form Factors: At Threshold

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$$\left. \frac{d\sigma_{\gamma^*}}{d\Omega_{\pi}} \right|_{\mathrm{th}} \propto \left[(E_{0+}^{\pi N})^2 + \epsilon \frac{Q^2}{(\omega_{\gamma^*}^{\mathrm{th}})^2} (L_{0+}^{\pi N})^2 \right]$$

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$$E_{0+}^{\pi N} \propto \frac{Q^2 \sqrt{Q^2 + 4m_N^2}}{m_N^3 f_\pi} G_1^{\pi N} \qquad \qquad L_{0+}^{\pi N} \propto \frac{Q^2 \sqrt{Q^2 + 4m_N^2}}{m_N^3 f_\pi} G_2^{\pi N}$$

LET expressions for the form factors at $\underline{\text{threshold}}$ can be related to the elastic form factors and the axial form factor:

• Obtained in the chiral limit $m_{\pi} = 0$

• Only valid at threshold for $Q^2 \sim 1 \,\mathrm{GeV}^2$

LETs Near Threshold

Correlation function:

$$\int dx \, e^{-iqx} \langle N(P')\pi(k)|j^{\rm em}_{\mu}(0)|p(P)\rangle$$



Near threshold, S and P wave contributions

$$\begin{split} \langle N(P')\pi(k)|j_{\mu}^{\rm em}(0)|p(P)\rangle \propto \bar{N}(P')\gamma_{5} \left\{ (\gamma_{\mu}q^{2} - q_{\mu}\not{q}) \frac{1}{m_{N}^{2}} G_{1}^{\pi N}(Q^{2}) - \frac{i\sigma_{\mu\nu}q^{\nu}}{2m_{N}} G_{2}^{\pi N}(Q^{2}) \right\} p(P) \\ + \bar{N}(P')\not{k}\gamma_{5}(\not{P}' + m_{N}) \left\{ F_{1}^{p}(Q^{2}) \left(\gamma_{\mu} - \frac{q_{\mu}\not{q}}{q^{2}}\right) + \frac{i\sigma_{\mu\nu}q^{\nu}}{2m_{N}} F_{2}^{p}(Q^{2}) \right\} p(P) \end{split}$$

- S-wave: generalized form factors from LCSR $(G_1^{\pi N} \text{ and } G_2^{\pi N})$
- P-wave: electromagnetic form factors $(F_1^p \text{ and } F_2^p)$
- Both S and P-wave multipoles are involved $(l = 0, 1, \cdots)$

Braun et al. Phys. Rev. D (2008).

CLAS Experiment e1-6: Analysis

Experimental difficulties:

- Very small cross sections
- High Bethe-Heitler contamination
- Poor ϕ_{π} resolution because $\theta_{\pi} \approx \theta_{\gamma} *$

Analysis Steps:

- Electron and proton identification
- Corrections Kinematic and Acceptance
- Pion Identification
 - Missing Mass Technique (epX)
 - Bethe-Heitler Subtractions



 $ep \to ep\pi^0$

Pion Identification





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Bethe-Heitler Subtraction

Assuming elastic scattering, we can compute θ_{proton} independent of incident and scattered electron energies.



Calculate deviation of measured proton angle from elastic scattering process

$$\Delta \theta_{1,2}^P \equiv \theta_{calc} - \theta_{meas}$$

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Bethe-Heitler Subtraction (continued)



After Bethe-Heitler Subtraction



- Select pions with $|M_X^2 \mu| < 3\sigma$
- Lose pions with BH subtraction cuts
- Use simulation to estimate % of lost pions
- Correct for this loss for each kinematic bin at the cross section level

Measure differential cross section for $ep \to ep\pi^0$:

$$\frac{d\sigma}{dE'd\Omega_e'd\Omega_\pi^*} = \Gamma \frac{d\sigma}{d\Omega_\pi^*}$$

Extract structure functions from reduced differential cross section:

$$\frac{d\sigma_{\gamma^*p \to p\pi^0}}{d\Omega^*_{\pi}} = \frac{p^*_{\pi}}{k^*_{\gamma}} \left(\frac{d\sigma_T}{d\Omega^*} + \varepsilon_L \frac{d\sigma_L}{d\Omega^*} + \varepsilon \frac{d\sigma_{TT}}{d\Omega^*} \cos 2\phi^*_{\pi} + \sqrt{2\varepsilon_L(\varepsilon+1)} \frac{d\sigma_{LT}}{d\Omega^*} \cos \phi^*_{\pi} \right)$$

- Obtain multipoles E_{0+} and L_{0+}
- Obtain form factors $G_1^{\pi N}$ and $G_2^{\pi N}$

Differential Cross Sections - $d\sigma/d\Omega$



Red points: experiment (dashed curve fit) · Blue curve: MAID 2007 Magenta curve: Braun 2008 · Green curve: Aznauryan 2009 Preliminary

Differential Cross Sections - $d\sigma/d\Omega$ (continued)



 $W = 1.23 \text{ GeV}, Q^2 = 2.75 \text{ GeV}^2$ Red points: experiment (dashed curve fit) · Blue curve: MAID 2007 Green curve: Aznauryan 2009 Preliminary

Integrated Cross Sections $\sigma(\pi^0 p)$



Preliminary

Red: experiment, Blue: MAID 2007, Magenta: Braun 2008, Green: Aznauryan 2009

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Integrated Cross Sections - $Q^6\sigma(\pi^0 p)$



Red: experiment, Blue: MAID 2007, Magenta: Braun 2008, Green: Aznauryan 2009

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Structure Functions



W = 1.09 GeV

Preliminary

Red: experiment, Blue: MAID 2007, Magenta: Braun 2008, Green: Aznauryan 2009

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- Pion electroproduction near threshold
- Test the applicability of LETs in $Q^2 \sim 1 10 \,\mathrm{GeV}^2$
- Very low statistics and small cross sections difficult
- Differential and integrated cross sections have been obtained
- Structure functions have been extracted
- Extract S-wave multipoles E_{0+} and L_{0+} that are directly related to the generalized form factors, $G_1^{\pi N}$ and $G_2^{\pi N}$, near threshold



"The cake is a lie." - Portal

Backup slides

Historical background: @ threshold (continued)

Bernard et al. Int. J. Mod. Phys. E4 (1995) 193-346



• rederived low energy theorems to $O(m_{\pi}^2)$

- used chiral perturbation theory
- yields better results at $Q^2 = 0$ (Vainshtein, Zakharov, 1970s; Scherer, Koch, 1990s)

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LCSR: Differential cross section

$$\frac{d\sigma_{\gamma^*}}{d\Omega_{\pi}} = \sigma_T + \epsilon \sigma_L + \sqrt{2\epsilon(1+\epsilon)}\sigma_{LT}\cos(\phi_{\pi}) + \epsilon \sigma_{TT}\cos(2\phi_{\pi}) + \lambda \sqrt{2\epsilon(1-\epsilon)}\sigma'_{LT}\sin(\phi_{\pi})$$

$$\begin{split} &\sigma_T \rightarrow G_1^{\pi N}, G_M^2 \\ &\sigma_L \rightarrow G_2^{\pi N}, G_E^2 \\ &\sigma_{LT} \rightarrow G_M, G_E, ReG_1^{\pi N}, ReG_2^{\pi N} \\ &\sigma_{TT} = 0 \\ &\sigma_{LT}' \rightarrow G_M, G_E, ImG_1^{\pi N}, ImG_2^{\pi N} \end{split}$$

- $\sigma_{TT} = 0$: D-wave contribution neglected
- σ'_{LT} : related to single-spin symmetry

e1-6: Vertex Corrections and Cuts



- Beam line = (0.09, -0.345, z) cm
- All sector midplanes are corrected to line up with the beamline

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e1-6: Vertex Corrections and Cuts



- Beam line = (0.09, -0.345, z) cm
- All sector midplanes are corrected to line up with the beamline
- Cut on $V_z \in (-8.0, -0.8)$ cm
- Cut on $|\Delta V_z(e-p)| < 0.74$ cm

e1-6: Empty Target Comparison



- Very loose cut on vertex $v_z \in (-8.0, -0.8)$ cm
- Include all cuts from analysis
- Total charge collected

 $\begin{array}{rcl} {\rm FCUP_{empty\ target}} & = & 2.214\,{\rm mC} \\ {\rm FCUP_{production}} & = & 21.287\,{\rm mC} \end{array}$

• Total contamination $\sim 2-5\%$

e1-6: Pion Loss Estimation



- BH cleanup cuts throw away good pions
- Estimate the pion loss using simulation: MAID 2007 model
- Ratio = Thrown/ Kept
- Ratio is highest at $\cos \theta_{\pi}^* \to 1$ and $\phi_{proton}^* \approx 180^\circ$ (*i.e.*, $\phi_{\pi}^* \approx 0^\circ$)
- Apply correction to each kinematic bin near threshold

e1-6: Elastic Cross Section $(ep \rightarrow eX)$



- Inclusive reaction: $ep \to eX$
- Compare with Bosted parameterization of form factors Phys. Rev. C 51, 409 (1995)
- Good agreement within $\pm 5\%$

e1-6: Elastic Cross Section $(ep \rightarrow ep)$



- Exclusive reaction: $ep \rightarrow ep$
- Proton detection inefficiencies
- Ad hoc overall correction $\sim 10\%$

e1-6: Bin Centering Corrections



- The cross sections vary inside bin
- Center of bin is not true center
- Correction factor:

$$R_{W,Q^2,\cos\theta,\phi} = \frac{\sigma_{center}}{\sigma_{average}}$$

• Average overall correction $\sim 10\%$

e1-6: Radiative Corrections - EXCLURAD



$$\sigma_{born} = \frac{\sigma_{meas}}{RC} = \sigma_{meas} \left(\frac{RAD_{gen}}{RAD_{rec}} \right) \times \left(\frac{NORAD_{gen}}{RAD_{gen}} \right) \tag{1}$$

- Corrections obtained from EXCLURAD using MAID 2007 model
- Radiative correction independent of vcut near threshold
- Correction is largest at $\cos\theta\sim-0.9$ because pion cross section goes to zero and BH dominates; is ϕ dependent
- About 20% overall correction

e1-6: χ^2 Distributions



$$\frac{d\sigma}{d\Omega_{\pi}^*} = A + B\varepsilon \cos 2\phi_{\pi}^* + C[2\varepsilon_L(\varepsilon+1)]^{1/2} \cos \phi_{\pi}^*$$

12 points in ϕ_{π}^* – 3 parameters = 9 d.o.f. Total number of fits = 5 Q^2 bins × 10 cos θ_{π}^* bins = 50.